

AMENDMENT
Serial Number: 10/043065
Filing Date: January 9, 2002

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Dkt: 303.684US3

Title: P-CHANNEL DYNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUNNEL OXIDES

IN THE DRAWINGS

Figure 5B is amended to remove an equation. Applicant has amended the specification to add the deleted equation. A complete set of Formal Drawings is enclosed herewith.



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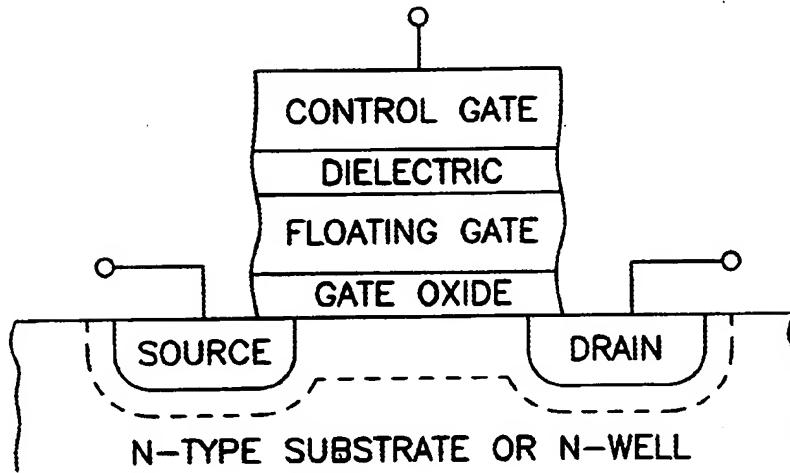


FIG. 1A
(PRIOR ART)
PMOS

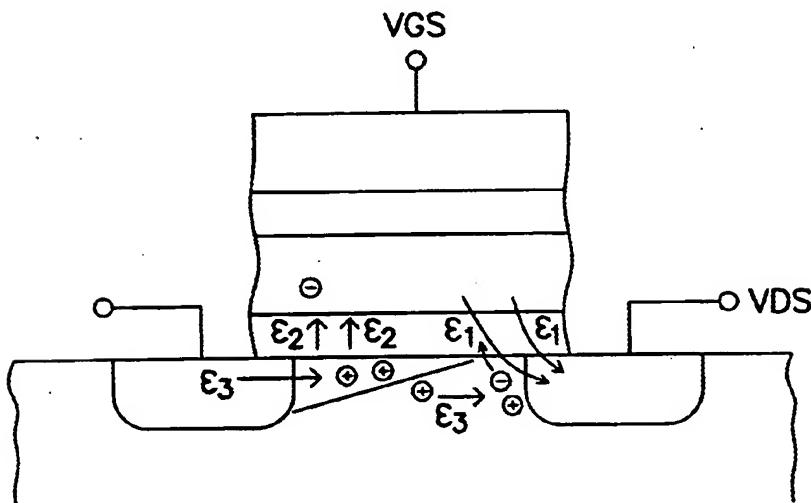
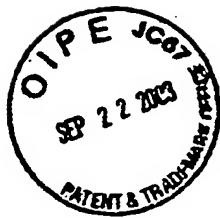


FIG. 1B
(PRIOR ART)



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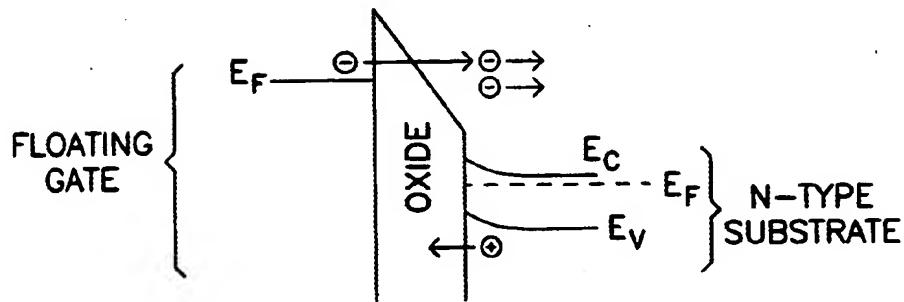


FIG. 2A
(PRIOR ART)

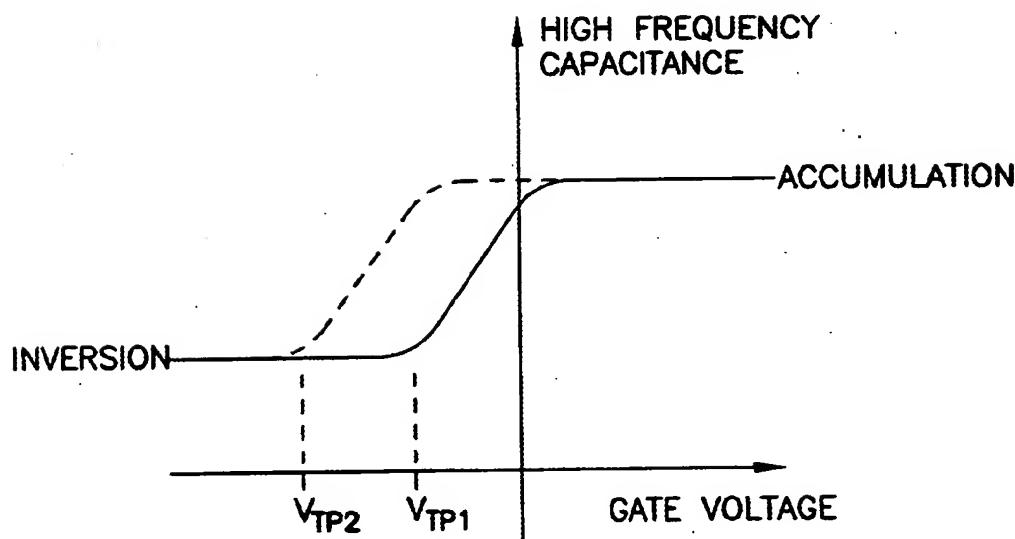


FIG. 2B
(PRIOR ART)



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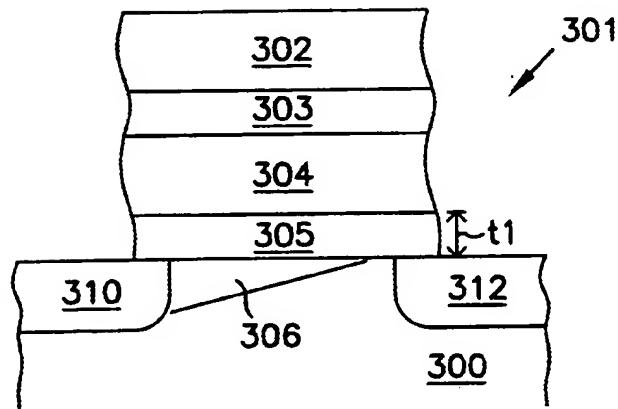


FIG. 3A

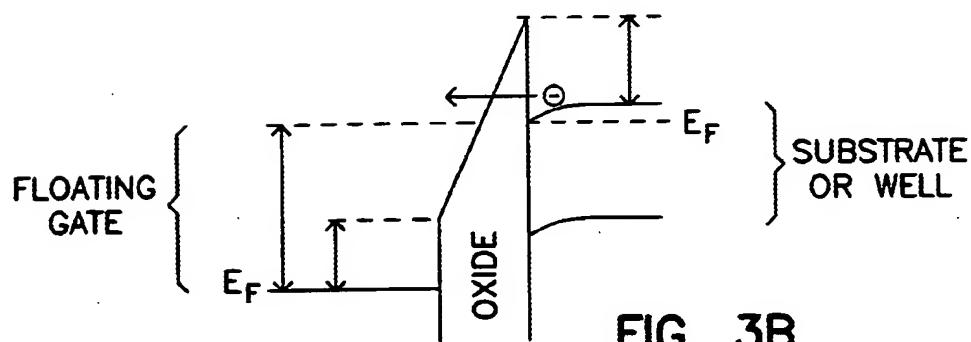


FIG. 3B

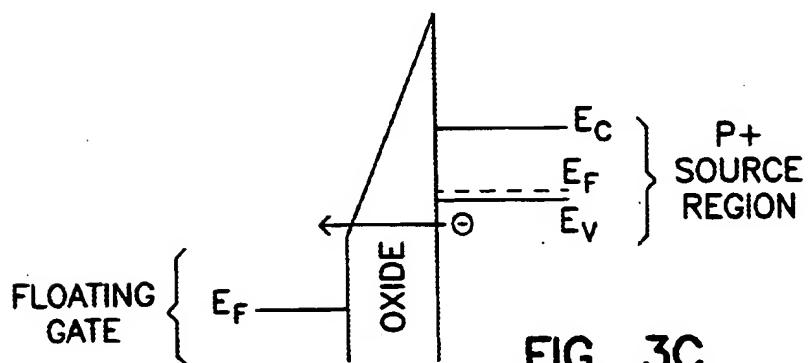


FIG. 3C



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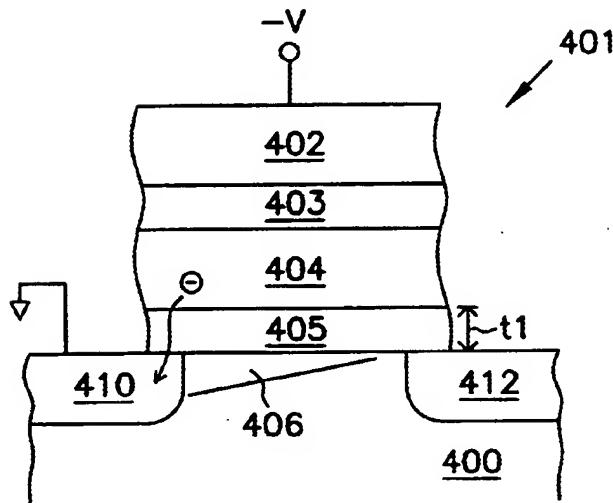


FIG. 4A

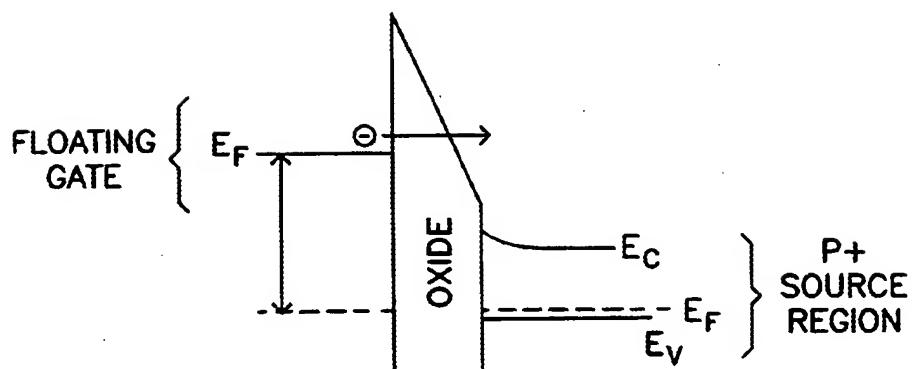


FIG. 4B

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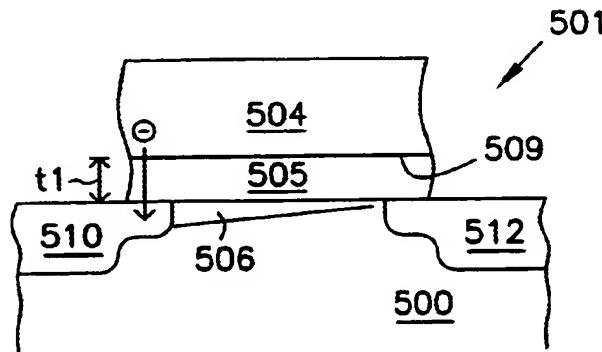


FIG. 5A

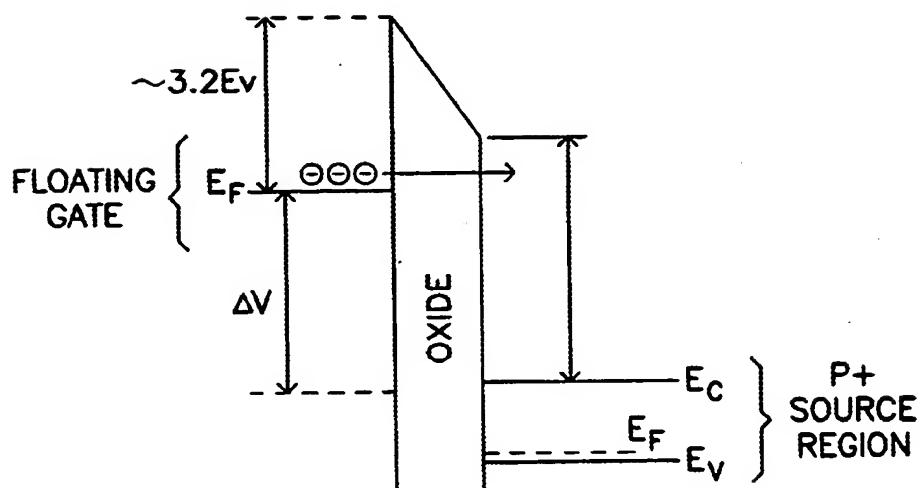
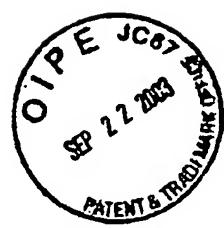


FIG. 5B



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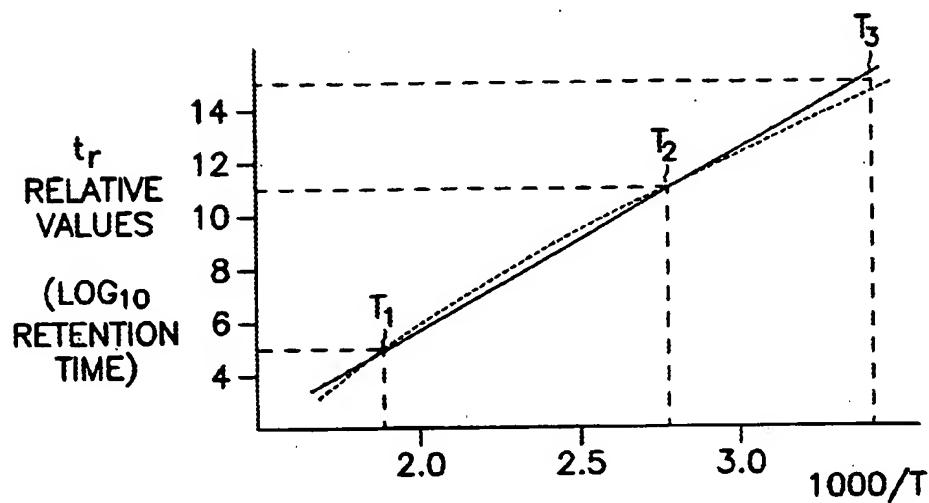


FIG. 6A

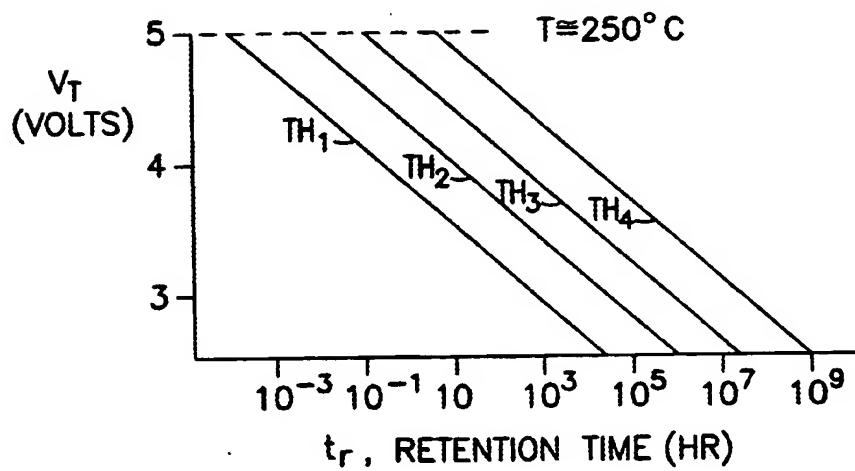


FIG. 6B



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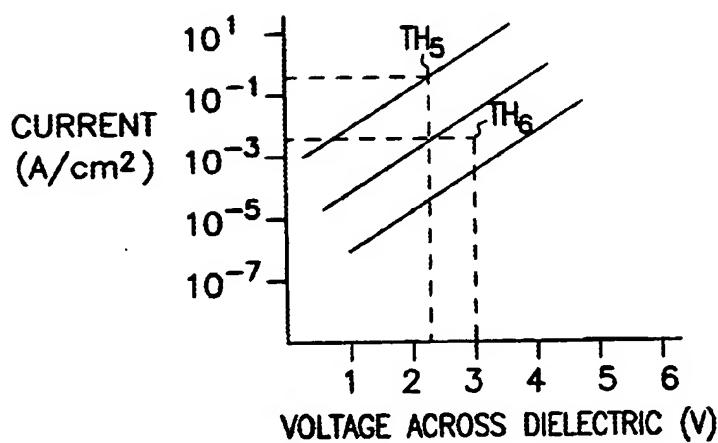


FIG. 7

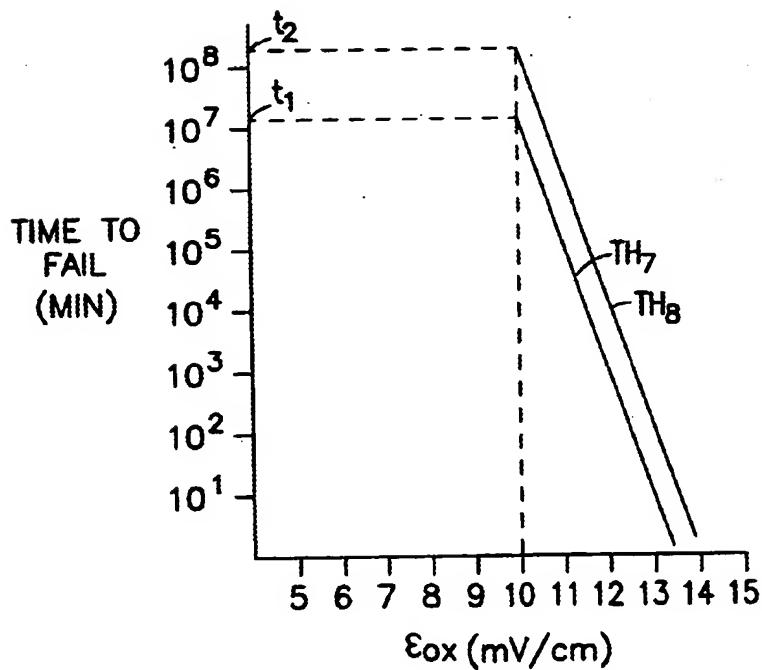


FIG. 8

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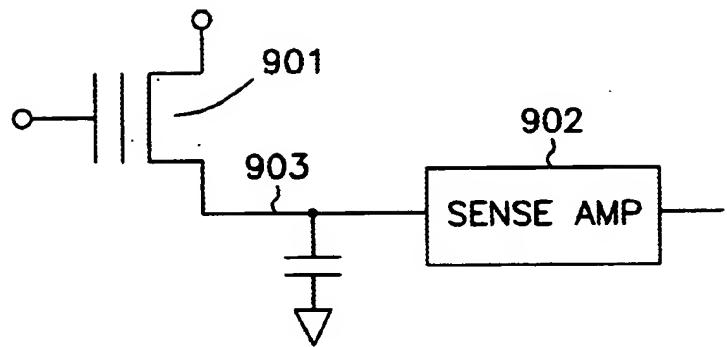


FIG. 9



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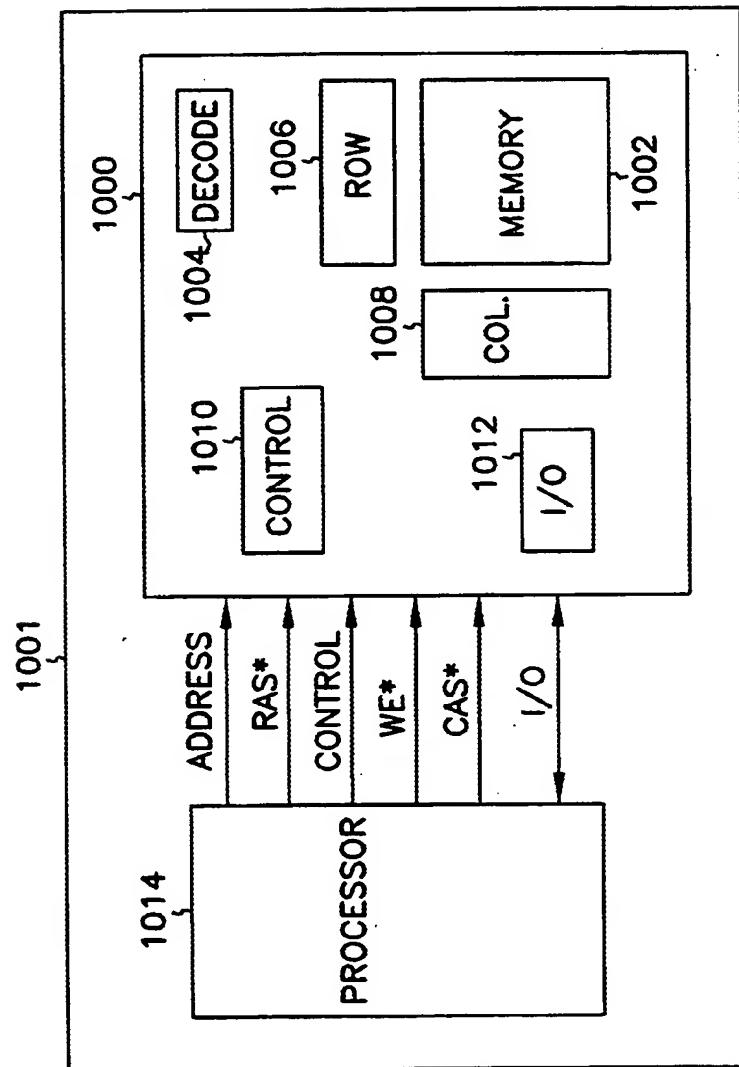


FIG. 10



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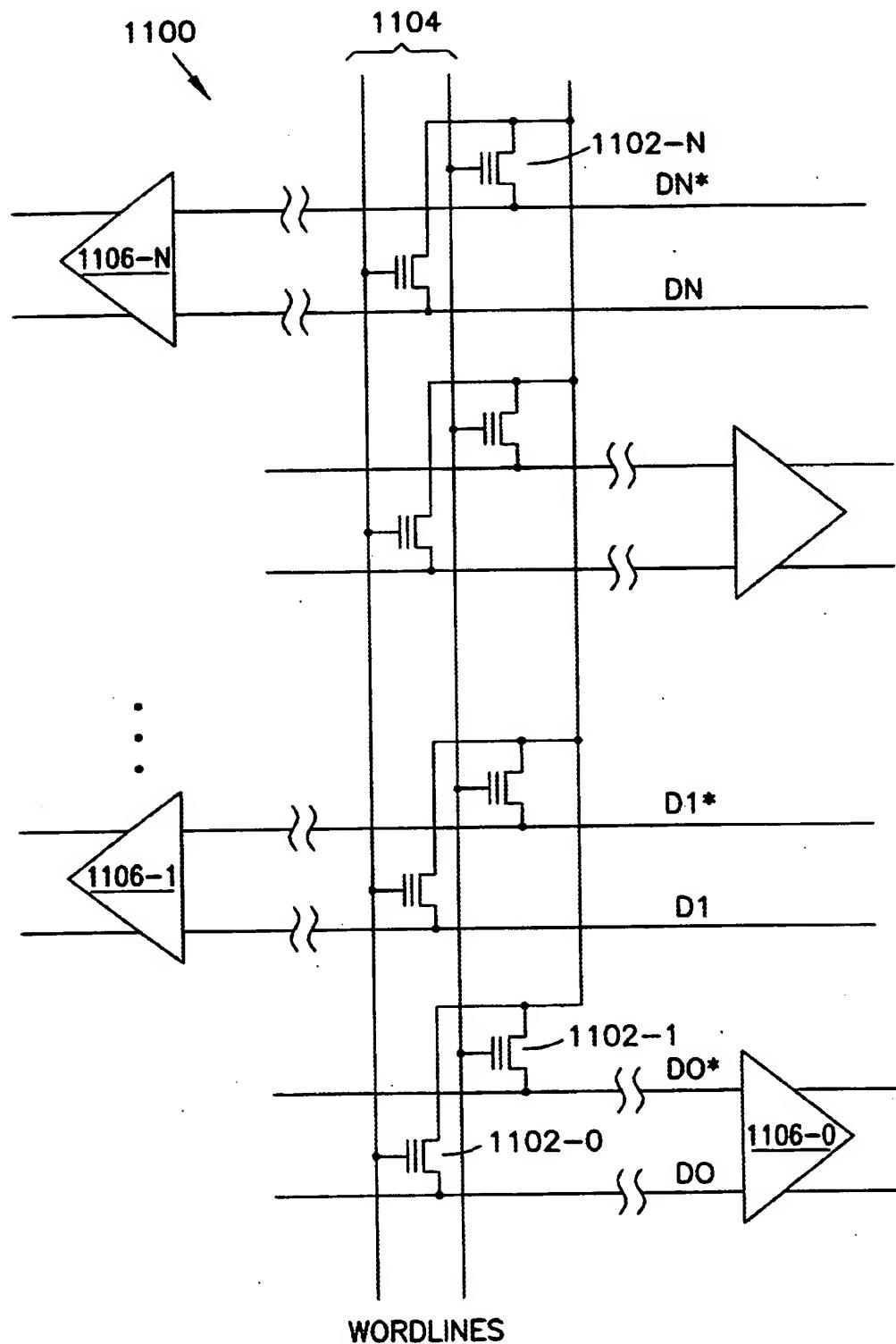


FIG. 11